LOW NOISE INFRARED DIODE LASER AT 975nm

RN-N-975/6~10W

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy

operation. They are used in measurement, communication, spectrum analysis, etc.

产品参数

RN-N-975/6~10W	
Wavelength (nm)	975±5
Operating mode	CW
Output power (mW)	>6, 6.5, 7, , 10
Power stability (rms, over 4 hours)	<0.5%, <1%, <2%
Transverse mode	Multimode
M ² factor	<20
Beam divergence, full angle (mrad)	<3.0
Beam diameter at the aperture (1/e²,mm)	5~8
Warm-up time (minutes)	<5
Beam height from base plate (mm)	68.5
Operating temperature (° $\mathbb C$)	10~35
Power supply (90-264VAC)	PSU-H-LED PSU-H-FDA
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional
Expected lifetime (hours)	10000
Warranty period	1 year

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